







	<h2>SI3853DV-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI3853DV-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 1.6A 6-TSOP</p> <p>Datenblätter:  SI3853DV-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 17719 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3853DV-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 20V 1.6A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	17719 pcs Stock
detaillierte Beschreibung	P-Channel 20V 1.6A (Ta) 830mW (Ta) Surface Mount
Serie	LITTLE FOOT®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	830mW (Ta)
Typ FET	P-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.6A (Ta)
Rds On (Max) @ Id, Vgs	200 mOhm @ 1.8A, 4.5V
VGS (th) (Max) @ Id	500mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	4nC @ 4.5V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI3853DV-T1-E3TR

SI3853DV-T1-E3 ist neu im Original, Suche SI3853DV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3853DV-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI3853DV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3851DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 1.6A 6-TSOP</p>	 <p>SI3851DV-T1-ES VISHAY VISHAY SOT-163</p>	 <p>SI3861BDV-T1-E3 Electro-Films (EFI) / Vishay IC LOAD SWITCH LVL SHIFT 6-TSOP</p>	 <p>SI3861BDV-T1-GE3 Vishay / Siliconix IC LOAD SWITCH LVL SHIFT 6-TSOP</p>
 <p>SI3853DV-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 1.6A 6-TSOP</p>	 <p>SI3853DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 1.6A 6-TSOP</p>	 <p>SI3853DV-T1 Vishay Precision Group SI3853DV-T1 VISHAY</p>	 <p>SI3853DV-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 1.6A 6-TSOP</p>

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SI3588DV-T1-E3	SI3588DV-T1-GE3	SI3588DV-T1-GE3	SI3590DV-T1-GE3	SI3590DV-T1-GE3
SI3801DV-T1	SI3803DV-T1	SI3805DV-T1	SI3805DV-T1-E3	SI3805DV-T1-E3
SI3812DV-T1-GE3	SI3812DV-T1-GE3	SI3850ADV-T1-E3	SI3850ADV-T1-E3	SI3850ADV-T1-GE3
SI3850ADV-T1-GE3	SI3850DV-T1	SI3850DV-T1-E3	SI3850DV-T1-GE3	SI3851DV
SI3851DV-T1	SI3851DV-T1-E3	SI3851DV-T1-E3	SI3851DV-T1-GE3	SI3853DV-T1-E3
SI3861BDV-T1-GE3	SI3861BDV-T1-GE3	SI3861DV-NL	SI3861DV-T1-E3	SI3863BDV-T1-GE3
SI3863DV-T1-E3	SI3863DV-T1-GE3	SI3865BDV-T1-E3	SI3865BDV-T1-E3	SI3865CDV-T1-GE3
SI3865CDV-T1-GE3	SI3865DV-T1	SI3865DV-T1-E3	SI3865DV-T1-GE3	SI3867DV-T1-E3
SI3867DV-T1-E3	SI3867DV-T1-GE3	SI3867DV-T1-GE3	SI3879DV-T1-E3	SI3879DV-T1-E3
SI3900DV	SI3900DV-T1-E3	SI3900DV-T1-E3	SI3900DV-T1-GE3	SI3900DV-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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